Reg. No. : $\square$

## Question Paper Code : X67557

B.E./B.Tech. DEGREE EXAMINATIONS, NOVEMBER/DECEMBER 2020

Third Semester
Electronics and Communication Engineering
EC1201 - DIGITAL ELECTRONICS
(Regulations 2008)
Time : Three Hours
Maximum : 100 Marks

## Answer ALL questions

PART - A

1. Convert $41.6875_{10}$ to binary.
2. Construct AND gate using NAND gates.
3. Draw the inverter logic circuit using n-channel MOS devices.
4. What is totem-pole output?
5. Draw the logic circuit for the expression $F=\bar{x} \bar{y} z+\bar{x} y z+x \bar{y}$
6. Define modulus of a counter.
7. Draw the logic diagram of D flipflop using NAND gates.
8. How does JK filip flop differ from an $\mathrm{S}-\mathrm{R}$ flip flop in its basic operation ?
9. Distinguish between EAPROM and EEPROM.
10. Write about FPGA.
PART - B
(5×16=80 Marks)
11. a) i) Design the circuit for one bit comparator.
ii) Design a full adder circuit using NAND gates only.
(OR)
b) i) Write a detailed technical note on the Hardware Description Language.
ii) What is Karnaugh Map ? A truth table has output 0 for input $\mathrm{ABCD}=0000,0010,1100,1101,1110,1111,0101,0111$. Simplify using Karnaugh Map and draw the simplified circuit.
12. a) Explain the construction and operation of DTL and TTL NAND gate. Also mention the characteristics of DTL and TTL families.
(OR)
b) i) Explain CMOS NAND and NOR gate operation.
ii) Explain the working of tristate logic.
13. a) i) Design and implement an $8 \times 1$ multiplexer using suitable gates.
ii) Design a 3 bit parity generator and checker circuit.
(OR)
b) i) Design and implement full subtractor using suitable gates.
ii) Design the logic diagram of magnitude comparator to compare two binary variables A and B accompanied by 3 bits each.
14. a) i) Design a synchronous decade counter to count in the following sequence. $1,0,2,3,4,8,7,6,5$.
ii) What is sequential circuit? Explain S-R and J K flip flop.
(OR)
b) i) Draw and explain 4-bit synchronous Up/Down counter.
ii) Design a serial 2's complementer with a shaft register and a flip-flop. The binary number is shifter out from one side and its 2's complement shifted into the other side of the shift register.
15. a) i) Draw the circuit of a BJT RAM cell and explain its operation.
ii) Give the classification of memory and explain the block diagram of ROM.
(OR)
b) Along with neat diagrams write a detailed technical note on the following
i) MOSFET RAM cell.
ii) FPGA.
